# TEXAS INSTRUMENTS

Data sheet acquired from Harris Semiconductor SCHS174B

February 1998 - Revised May 2003

## Features

- Common Clock and Asynchronous Master Reset
- Positive Edge Triggering
- Buffered Inputs
- Fanout (Over Temperature Range)
  - Standard Outputs ..... 10 LSTTL Loads
  - Bus Driver Outputs ..... 15 LSTTL Loads
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity: N<sub>IL</sub> = 30%, N<sub>IH</sub> = 30% of V<sub>CC</sub> at V<sub>CC</sub> = 5V
- HCT Types
  - 4.5V to 5.5V Operation
  - Direct LSTTL Input Logic Compatibility, V<sub>IL</sub>= 0.8V (Max), V<sub>IH</sub> = 2V (Min)
  - CMOS Input Compatibility, II  $\leq$  1µA at VOL, VOH

# CD54HC273, CD74HC273, CD54HCT273, CD74HCT273

# High-Speed CMOS Logic Octal D-Type Flip-Flop with Reset

### Description

The 'HC273 and 'HCT273 high speed octal D-Type flip-flops with a direct clear input are manufactured with silicon-gate CMOS technology. They possess the low power consumption of standard CMOS integrated circuits.

Information at the D inputis transferred to the Q outputs on the positive-going edge of the clock pulse. All eight flip-flops are controlled by a common clock (CP) and a common reset ( $\overline{\text{MR}}$ ). Resetting is accomplished by a low voltage level independent of the clock. All eight Q outputs are reset to a logic 0.

#### **Ordering Information**

PART NUMBER	TEMP. RANGE ( <sup>o</sup> C)	PACKAGE
CD54HC273F3A	-55 to 125	20 Ld CERDIP
CD74HC273E	-55 to 125	20 Ld PDIP
CD74HC273M	-55 to 125	20 Ld SOIC
CD74HC273M96	-55 to 125	20 Ld SOIC
CD54HCT273F3A	-55 to 125	20 Ld CERDIP
CD74HCT273E	-55 to 125	20 Ld PDIP
CD74HCT273M	-55 to 125	20 Ld SOIC
CD74HCT273M96	-55 to 125	20 Ld SOIC

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel.

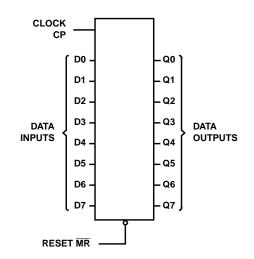
#### Pinout

		HC273, CD54 (CERDIP) HC273, CD74 (PDIP, SOIC TOP VIEW	HC	
			1	
MR	1		20	Vcc
QO	2		19	Q7
D0	3		18	D7
D1	4		17	D6
Q1	5		16	Q6
Q2	6		15	Q5
D2	7		14	D5
D3	8		13	D4
Q3	9		12	Q4
GND	10		11	СР

#### CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures.

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# Functional Diagram



#### TRUTH TABLE

	INPUTS		OUTPUT
RESET (MR)	CLOCK CP	DATA D <sub>n</sub>	Q
L	Х	Х	L
н	$\uparrow$	н	Н
н	$\uparrow$	L	L
Н	L	Х	Q <sub>0</sub>

H = High Voltage Level, L = Low Voltage Level, X = Don't Care,  $\uparrow$  = Transition from Low to High Level, Q<sub>0</sub> = Level Before the Indicated Steady-State Input Conditions Were Established.

#### **Absolute Maximum Ratings**

DC Supply Voltage, V <sub>CC</sub>
For $V_1 < -0.5V$ or $V_1 > V_{CC} + 0.5V$ ±20mA
DC Output Diode Current, I <sub>OK</sub>
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$
DC Drain Current, per Output, I <sub>O</sub>
For -0.5V < V <sub>O</sub> < V <sub>CC</sub> + 0.5V±25mA
DC Output Source or Sink Current per Output Pin, IO
For $V_{O} > -0.5V$ or $V_{O} < V_{CC} + 0.5V$
DC V <sub>CC</sub> or Ground Current, I <sub>CC</sub> ±50mA

## **Operating Conditions**

Temperature Range, T <sub>A</sub> 55°C to 125°C
Supply Voltage Range, V <sub>CC</sub>
HC Types2V to 6V
HCT Types
DC Input or Output Voltage, VI, VO 0V to VCC
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

#### **Thermal Information**

Thermal Resistance (Typical, Note 1)	θ <sub>JC</sub> ( <sup>o</sup> C/W)
E (PDIP) Package	69
M (SOIC) Package	58
Maximum Junction Temperature	150 <sup>0</sup> C
Maximum Storage Temperature Range65	<sup>o</sup> C to 150 <sup>o</sup> C
Maximum Lead Temperature (Soldering 10s)	300 <sup>0</sup> C
(SOIC - Lead Tips Only)	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

## **DC Electrical Specifications**

			ST ITIONS			25 <sup>0</sup> C		-40 <sup>0</sup> C 1	O 85 <sup>0</sup> C	-55 <sup>0</sup> С Т	O 125 <sup>0</sup> C	
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
HC TYPES	-		-									
High Level Input	V <sub>IH</sub>	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	V <sub>IL</sub>	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	V <sub>OH</sub>	V <sub>IH</sub> or	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
Voltage CMOS Loads		VIL	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Voltage TTL Loads			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V <sub>OL</sub>	V <sub>IH</sub> or	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads		VIL	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output	Output	4	4.5	-	-	0.26	-	0.33	-	0.4	V	
Voltage TTL Loads			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V <sub>CC</sub> or GND	-	6	-	-	±0.1	-	±1	-	±1	μA
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	6	-	-	8	-	80	-	160	μA

		TEST CONDITIONS			25 <sup>0</sup> C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES												
High Level Input Voltage	VIH	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V <sub>IL</sub>	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V <sub>CC</sub> to GND	0	5.5	-	-	±0.1	-	±1	-	±1	μA
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	5.5	-	-	8	-	80	-	160	μA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI <sub>CC</sub> (Note 2)	V <sub>CC</sub> -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μA

NOTE:

2. For dual-supply systems theoretical worst case (V<sub>I</sub> = 2.4V, V<sub>CC</sub> = 5.5V) specification is 1.8mA.

#### HCT Input Loading Table

INPUT	UNIT LOADS
MR	1.5
Data	0.4
СР	1.5

NOTE: Unit Load is  $\Delta I_{CC}$  limit specified in DC Electrical Specifications table, e.g., 360µA max at 25<sup>o</sup>C.

## Prerequisite For Switching Specifications

		TEST	TEST V <sub>CC</sub>	25 <sup>0</sup> C		-40°C TO 85°C		-55°C TO 125°C			
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES	-				-		-	-	-	-	
Maximum Clock Frequency (Figure 1)	f <sub>MAX</sub>	-	2	6	-	-	5	-	4	-	MHz
			4.5	30	-	-	25	-	20	-	MHz
			6	35	-	-	29	-	23	-	MHz
MR Pulse Width	t <sub>W</sub>	-	2	60	-	-	75	-	90	-	ns
(Figure 1)			4.5	12	-	-	15	-	18	-	ns
			6	10	-	-	13	-	15	-	ns

		TEST	v <sub>cc</sub>		25°C	;	-40 <sup>0</sup> C 1	O 85°C	-55 <sup>0</sup> С Т	O 125 <sup>0</sup> C	
PARAMETER	SYMBOL	-	s (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
Clock Pulse Width (Figure 1)	t <sub>W</sub>	-	2	80	-	-	100	-	120	-	ns
			4.5	16	-	-	20	-	24	-	ns
			6	14	-	-	17	-	20	-	ns
Set-up Time Data to Clock	ts∪	-	2	60	-	-	75	-	70	-	ns
(Figure 5)			4.5	12	-	-	15	-	18	-	ns
			6	10	-	-	13	-	15	-	ns
Hold Time, Data to Clock	tH	-	2	3	-	-	3	-	3	-	ns
(Figure 5)			4.5	3	-	-	3	-	3	-	ns
			6	3	-	-	3	-	3	-	ns
Removal Time, MR to Clock	t <sub>REM</sub>	-	2	50	-	-	65	-	75	-	ns
			4.5	10	-	-	13	-	15	-	ns
			6	9	-	-	11	-	13	-	ns
HCT TYPES	-										
Maximum Clock Frequency (Figure 2)	f <sub>MAX</sub>	-	4.5	25	-	-	20	-	16	-	MHz
MR Pulse Width (Figure 2)	tw	-	4.5	12	-	-	15	-	18	-	ns
Clock Pulse Width (Figure 2)	t <sub>w</sub>	-	4.5	20	-	-	25	-	30	-	ns
Set-up Time Data to Clock (Figure 6)	ts∪	-	4.5	12	-	-	15	-	18	-	ns
Hold Time, Data to Clock (Figure 6)	tH	-	4.5	3	-	-	3	-	3	-	ns
Removal Time, MR to Clock	t <sub>REM</sub>	-	4.5	10	-	-	13	-	15	-	ns
Switching Specification	15 Input tr. tr	6ns									
									-55°	сто	
		TEST			25 <sup>0</sup>	С	-40°C	ГО 85 <sup>0</sup> С	125		
PARAMETER	SYMBOL	CONDITIONS	V <sub>CC</sub> (V)	) Т	YP	MAX	м	AX	м	۹X	UNITS
HC TYPES											
Propagation Delay,	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2		-	150	1	90	22	25	ns
Clock to Output (Figure 3)			4.5		-	30	;	38	4	5	ns
			6		-	26	:	30	3	8	ns
	ľ	C <sub>L</sub> = 15pF	5	1	2	-		-		-	ns
Propagation Delay,	t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2		-	150	1	90	22	25	ns
MR to Output (Figure 3)			4.5		-	30	;	38	4	5	ns
× • • • /			6		-	26	:	30	3	8	ns
Output Transition Time	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	2		-	75	9	95	1'	10	ns
(Figure 3)			4.5		-	15	· ·	19	2	2	ns
		ļ	-	_		-					-

6

-

5

-

 $C_L = 15 pF$ 

Input Capacitance

Maximum Clock Frequency

CI

 $\mathsf{f}_{\mathsf{MAX}}$ 

13

10

-

-

-

60

16

10

-

19

10

-

ns

pF

MHz

		TEST	V <sub>CC</sub> (V)	25	°C	-40°C TO 85°C	-55 <sup>0</sup> C TO 125 <sup>0</sup> C	
PARAMETER	SYMBOL	CONDITIONS		TYP	МАХ	MAX	MAX	
Power Dissipation Capacitance (Notes 3, 4)	C <sub>PD</sub>	-	5	25	-	-	-	pF
HCT TYPES						-		•
Propagation Delay, t <sub>P</sub> Clock to Output (Figure 4)	t <sub>PLH</sub> , t <sub>PHL</sub>	$C_L = 50 pF$	4.5	-	30	38	45	ns
		C <sub>L</sub> = 15pF	5	12	-	-	-	ns
Propagation Delay, $\overline{\text{MR}}$ to Output (Figure 4)	<sup>t</sup> PHL	C <sub>L</sub> = 50pF	4.5	-	32	40	48	ns
Output Transition Time	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	4.5	-	15	19	22	ns
Input Capacitance	C <sub>IN</sub>	-	-	-	10	10	10	pF
Maximum Clock Frequency	f <sub>MAX</sub>	C <sub>L</sub> = 15pF	5	50	-	-	-	MHz
Power Dissipation Capacitance (Notes 3, 4)	C <sub>PD</sub>	-	5	25	-	-	-	pF

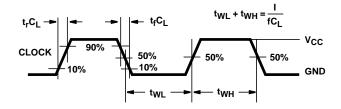
Switching Specifications Input  $t_r$ ,  $t_f = 6ns$  (Continued)

NOTES:

3.  $C_{\mbox{PD}}$  is used to determine the dynamic power consumption, per flip-flop.

4.  $P_D = C_{PD} V_{CC}^2 f_i + \Sigma (C_L V_{CC}^2 + f_0)$  where  $f_i =$  Input Frequency,  $f_O =$  Output Frequency,  $C_L =$  Output Load Capacitance,  $V_{CC} =$  Supply Voltage.

## Test Circuits and Waveforms



NOTE: Outputs should be switching from 10% V<sub>CC</sub> to 90% V<sub>CC</sub> in accordance with device truth table. For  $f_{MAX}$ , input duty cycle = 50%.

FIGURE 1. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

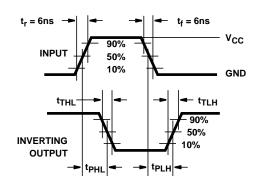
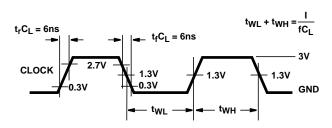
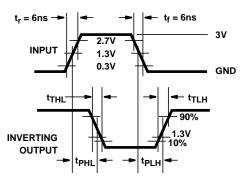


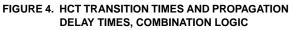
FIGURE 3. HC AND HCU TRANSITION TIMES AND PROPAGA-TION DELAY TIMES, COMBINATION LOGIC

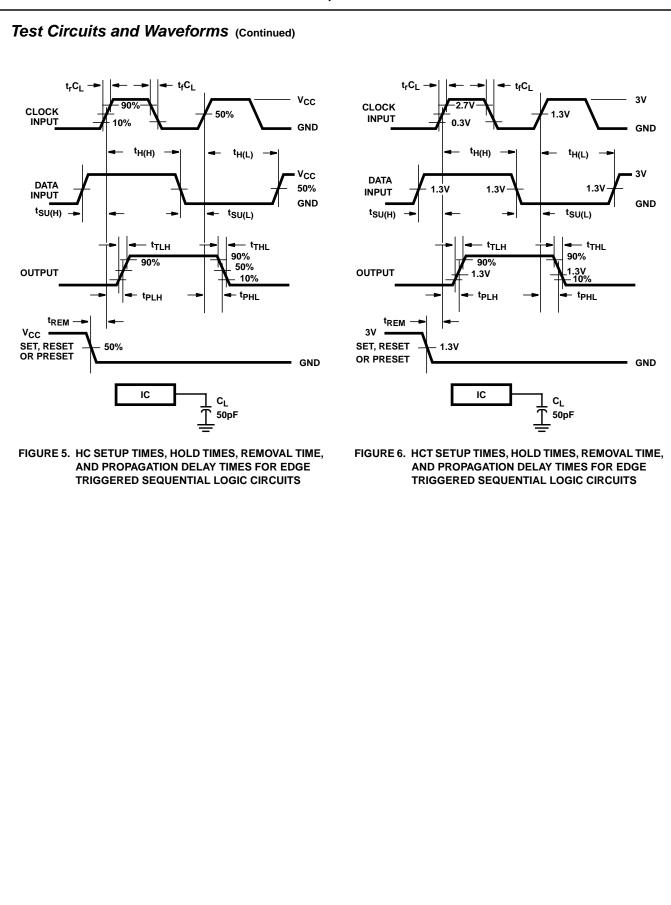


NOTE: Outputs should be switching from 10% V<sub>CC</sub> to 90% V<sub>CC</sub> in accordance with device truth table. For  $f_{MAX}$ , input duty cycle = 50%.

FIGURE 2. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH







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### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3</sup>
5962-8772501RA	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HC273F	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HC273F3A	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HCT273F	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HCT273F3A	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD74HC273E	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC273EE4	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC273M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC273M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC273M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HC273M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HC273ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HC273MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC273SM	OBSOLETE	SSOP	DB	20		Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT273E	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT273EE4	ACTIVE	PDIP	Ν	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT273M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT273M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT273M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT273M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT273ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
CD74HCT273MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN

<sup>(1)</sup> The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/product content for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

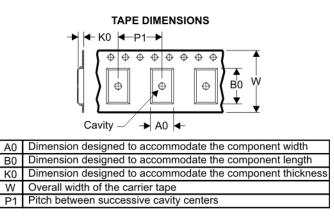
<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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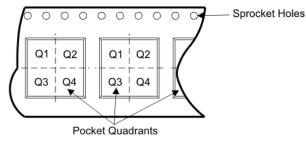
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## TAPE AND REEL BOX INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

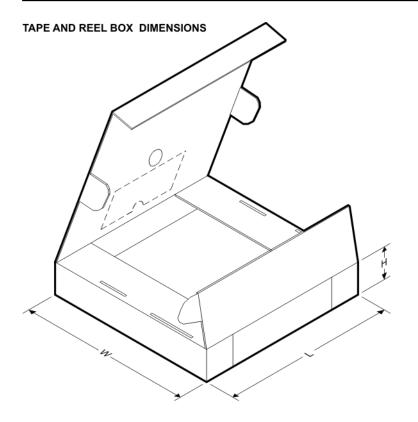


Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC273M96	DW	20	SITE 41	330	24	10.8	13.0	2.7	12	24	Q1
CD74HCT273M96	DW	20	SITE 41	330	24	10.8	13.0	2.7	12	24	Q1



# PACKAGE MATERIALS INFORMATION

4-Oct-2007



Device	Package	Pins	Site	Length (mm)	Width (mm)	Height (mm)
CD74HC273M96	DW	20	SITE 41	346.0	346.0	41.0
CD74HCT273M96	DW	20	SITE 41	346.0	346.0	41.0

J (R-GDIP-T\*\*) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

# N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- $\triangle$  The 20 pin end lead shoulder width is a vendor option, either half or full width.



DW (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AC.



# **MECHANICAL DATA**

MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001

## DB (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



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